

Supporting Information

for

Nitrogen-doped graphene films from chemical vapor deposition of pyridine: influence of process parameters on the electrical and optical properties

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Results of the Raman spectral fittings

Table S1: Raman properties of pyridine-CVD graphene films.

Samples		Raman parameters									
H ₂	T (°C)	Γ_D (cm ⁻¹)	ω_D (cm ⁻¹)	Γ_G (cm ⁻¹)	ω_G (cm ⁻¹)	Γ_{2D} (cm ⁻¹)	ω_{2D} (cm ⁻¹)	$I_{D/G}$	$I_{2D/G}$	$I_{D/D'}$	L_a [nm]
1 sccm	930	28.1	1343.7	20.0	1585.5	34.5	2682.0	0.92	1.55	3.68	15.26
	1000	31.2	1349.6	17.2	1584.3	36.6	2690.7	0.20	0.69	2.51	54.28
	1070	32.2	1351.5	16.1	1583.2	37.8	2693.4	0.14	0.6	2.14	73.20
100 sccm	930	28.7	1344.3	22.5	1586.0	39.4	2682.6	1.16	1.29	4.42	13.31
	1000	29.7	1348.2	17.3	1583.2	33.1	2690.8	0.17	0.86	3.19	66.27
	1070	33.5	1350.8	17.2	1582.3	40.4	2693.8	0.08	0.75	2.57	124.74

Table S2: Raman ratios of ethanol-CVD graphene films.

Samples		Raman ratios		
H ₂	T (°C)	$I_{D/G}$	$I_{2D/G}$	$I_{D/D'}$
1 sccm	930	0.68	0.89	3.41
	1000	0.13	0.84	2.17
	1070	0.05	0.89	1.67
100 sccm	930	0.25	1.15	2.88
	1000	0.19	0.86	3.80
	1070	0.06	0.70	2.0